

Current Sensor Automotive Current Sense Amplifier

BD1422xG-C Series

General Description

The BD1422xG-C is a current sense amplifier series.

This device operates from a single 2.7 V to 5.5 V power supply.

It has wide common mode voltage range from -14 V to +40 V, outputs analog voltage. The gains are 3 types from 25 V/V to 100 V/V.

The matched gain resistor minimizes gain error and offset voltage.

In additionally, the low input bias current is 1 µA that reduces the offset on the path to shunt resistor.

Features

- AEC-Q100 Qualified(Note 1)
- Wide Common Mode Voltage Range
- **High Accuracy**
- Low Offset Voltage
- Low Input Bias Current (Note 1) Grade 1

Applications

- Automotive 12 V Battery
- **Telecom Equipment**

Key Specifications

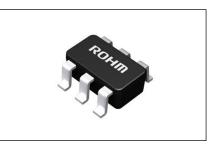
- VDD Voltage Range: 2.7 V to 5.5 V
 - 240 µA (Typ) Quiescent Current:
- Common Mode Voltage Range: -14 V to +40 V
- Gain: 25 V/V to 100 V/V 3 types (Typ)
- Gain Accuracy: ±1.0 % (Max)
- Operating Temperature Range: -40 °C to +125 °C

1	Product Name	Gain (Typ)
	BD14220G-C	25 V/V
	BD14221G-C	50 V/V
	BD14222G-C	100 V/V

Package

SSOP6

W (Typ) x D (Typ) x H (Max) 2.9 mm x 2.8 mm x 1.25 mm



Typical Application Circuit Adjust the bypass capacitor value as necessary, according to power supply VDD[noise conditions, etc. 0.1 µF VINP OUT Micro ADC Controlle VINM REF LOAD GND

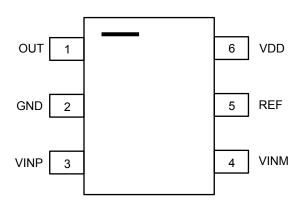
OProduct structure : Silicon integrated circuit OThis product has no designed protection against radioactive rays.

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Pin Configuration





Pin Descriptions

Pin No.	Pin Name	Function					
1	OUT	Current detection output					
2	GND	Ground					
3	VINP	Voltage input of supply side of shunt resistor					
4	VINM	Voltage input of load side of shunt resistor					
5	REF	Reference voltage					
6	VDD	Power supply ^(Note 2)					
(Note 2) Dispose a by	Vote 2) Dispose a hypass canacitor between VDD and GND						

(Note 2) Dispose a bypass capacitor between VDD and GND.

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V _{DD}	7.0	V
Common Mode Voltage	Vсм	-14 to +40	V
Differential Voltage (V _{VINP} -V _{VINM})	VSENSE	±28	V
REF Pin Voltage	V _{REF}	-0.3 to (V _{DD} + 0.3) or +7.0 Whichever is less	V
Input Current Into Any Pin	l _{in}	±5	mA
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance^(Note 3)

Decemptor	Symbol	Thermal Res	Unit		
Parameter	Symbol	1s ^(Note 5)	2s2p ^(Note 6)	Unit	
SSOP6					
Junction to Ambient	θյΑ	376.5	185.4	°C/W	
Junction to Top Characterization Parameter ^(Note 4)	Ψ_{JT}	40	30	°C/W	

(Note 3) Based on JESD51-2A (Still-Air).

(Note 4) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 5) Using a PCB board based on JESD51-3. (Note 6) Using a PCB board based on JESD51-7.

Note of Using a FCB board based on JESD31-7.					
Layer Number of Measurement Board	Material	Board Size			
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt			
Тор					
Copper Pattern	Thickness				
Footprints and Traces	70 µm				
Layer Number of Measurement Board	Material	Board Size			
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt			
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	

Thickness 70 µm

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Power Supply Voltage	Vdd	2.7	5.0	5.5	V	
Common Mode Voltage	V _{CM}	-14	+12	+40	V	VINP, VINM
Operating Temperature	Topr	-40	+25	+125	°C	

Electrical Characteristics

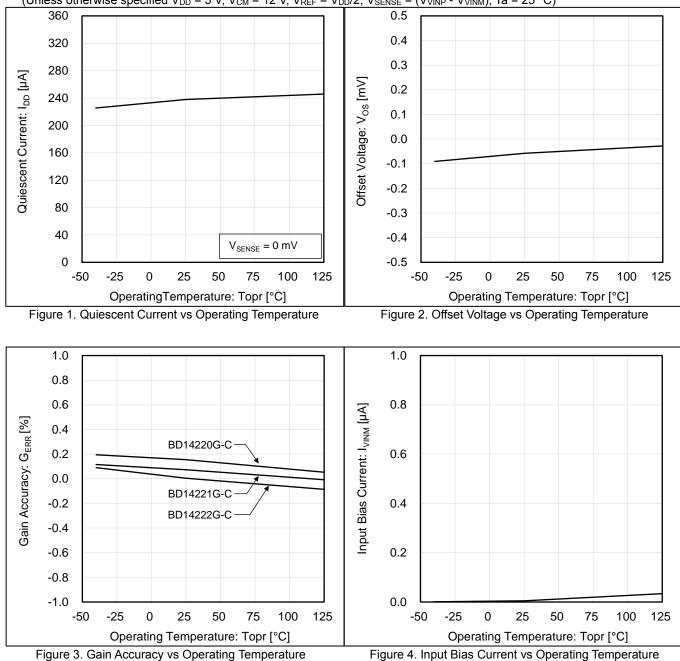
(Unless otherwise specified V_{DD} = 5 V, V_{CM} = 12 V, V_{REF} = V_{DD}/2, V_{SENSE} = (V_{VINP} - V_{VINM}), Ta = 25 °C)

Parameter		Symbol	Min	Тур	Max	Unit	Conditions
Power Supply		1		1			
Quiescent Cur	rent	IDD	-	240	360	μA	V _{SENSE} = 0 mV
Current Sense	Amplifier						
Offset Voltage		Vos	-	-	±0.5	mV	RTI ^(Note 7) , V _{SENSE} = 0 mV Ta = -40 °C to +125 °C
	BD14220G-C		-	25	-		
Gain	BD14221G-C	GAIN	-	50	-	V/V	
	BD14222G-C		-	100	-		
Gain Accuracy		G _{ERR}	-	-	±1.0	%	V _{OUT} = 0.5 V to V _{DD} - 0.5 V Ta = -40 °C to +125 °C
Nonlinearity E	rror	Lin	-	±0.01	-	%	Vout = 0.5 V to V _{DD} - 0.5 V
Input Bias Current		IVINM	-	-	±1.0	μA	V _{SENSE} = 0 mV Ta = -40 °C to +125 °C
Band Width		BW	-	40	-	kHz	
High-level Output Voltage		Vout_h	V _{DD} - 0.03	-	-	V	OUT, R∟ = 10 kΩ pulldown
Low-level Output Voltage		V _{OUT_L}	-	-	GND + 0.05	V	OUT, R _L = 10 kΩ pullup

(Note 7) RTI = Referred To Input

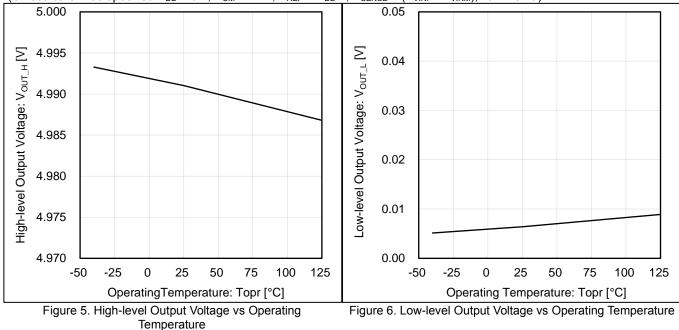
Typical Performance Curves





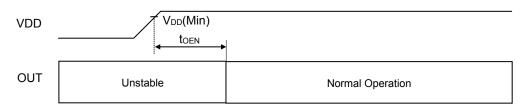
Typical Performance Curves - continued

(Unless otherwise specified V_{DD} = 5 V, V_{CM} = 12 V, V_{REF} = $V_{DD}/2$, V_{SENSE} = (V_{VINP} - V_{VINM}), Ta = 25 °C)



Timing Chart

- 1. Control Sequence
- 1.1 Power supply start-up sequence





Stable time of OUT (toen) should be 1 ms or more.

1.2 Power supply off sequence

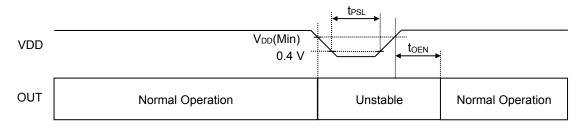


Figure 8. Timing Chart at Power OFF

Power off time (t_{PSL}) should be 1 ms or more.

If V_{DD} is under the recommended operating condition, LSI is unstable state. In that case, set Power OFF and ON again. When the power is ON again, the period of V_{DD} < 0.4 V should be t_{PSL} or more.

Application Example

This IC has the structure specialized for Current Sense Amplifier and has the following features. Common mode voltage range is maximum 40 V with V_{DD} of maximum 5.5 V, therefore it is possible to detect the current flowing in a power supply line exceeding V_{DD} voltage. And its input bias current is very low.

This IC amplifies the voltage difference across the shunt resistor between VINP and VINM and outputs a voltage with the REF pin as reference voltage.

If the current flows from VINP to VINM, OUT pin voltage is higher than REF pin voltage. If the current flows from VINM to VINP, OUT pin voltage is lower than REF pin voltage. When the voltages of VINP and VINM are equal, OUT pin voltage is equal to REF pin voltage.

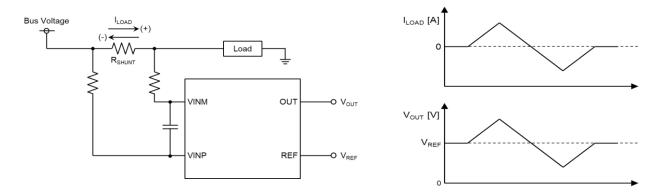


Figure 9. Basic Explanation

Vout is calculated by the below formula.

$$V_{OUT} = (R_{SHUNT} \times I_{LOAD} \times G_{AIN}) + V_{REF}$$

Where,

 R_{SHUNT} is the Shunt resistance I_{LOAD} is the Load current G_{AIN} is the Gain of Current Sense Amplifier V_{REF} is the REF pin voltage

Also, V_{OUT} needs to be GND < V_{OUT} < V_{DD} .

 V_{OUT} is clipped to Low-level Output Voltage (V_{\text{OUT}_L}) when it's under GND.

Vout is clipped to High-level Output Voltage (V_{OUT_H}) when it's over V_{DD}.

To accurately sense the current through the shunt resistor, a 4-terminal Kelvin connection must be used to avoid errors in the impedance of the current path.

For stability, dispose and connect a bypass capacitor for removing power source noise close to IC.

Selection of shunt resistor

Shunt resistor R_{SHUNT} should be selected considering the accuracy of measuring current and the maximum power dissipation according to an application.

If the value of shunt resistor is high, it minimizes the influence of offset and increases the accuracy of measuring current. If the value of shunt resistor is low, it reduces the power dissipation of V_{DD} .

I/O Equivalence Circuits

Pin Name	Equivalence Circuit Diagram	Pin Name	Equivalence Circuit Diagram
OUT		VINP VINM	┖╺╾╼ ¥ ŧ
REF			

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes - continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

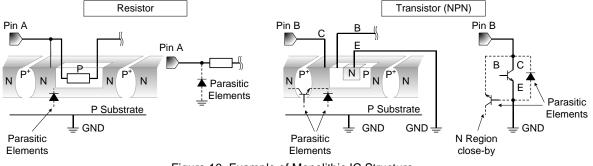
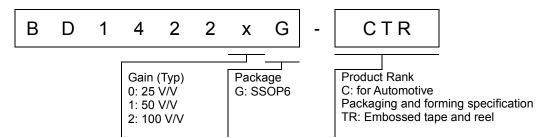


Figure 10. Example of Monolithic IC Structure

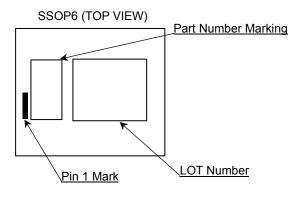
11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

Ordering Information

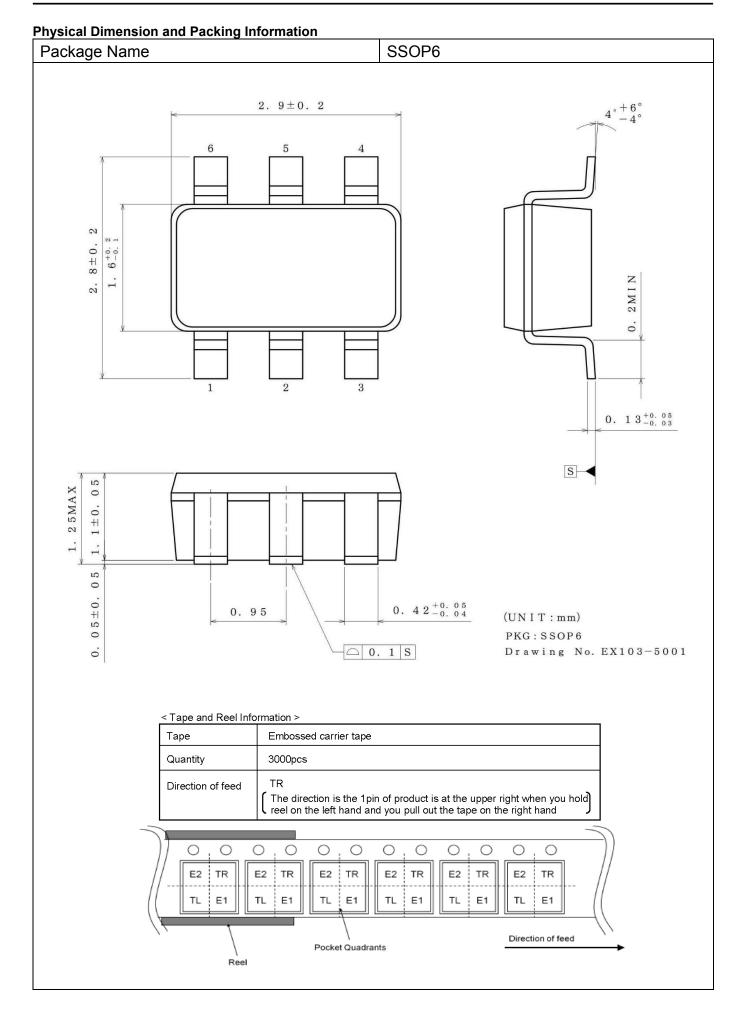


Marking Diagram



Part Number Marking	Package	Orderable Part Number
GT	SSOP6	BD14220G-CTR
GU		BD14221G-CTR
GV		BD14222G-CTR

Datasheet



Revision History

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Date	Revision	Changes
19.Jan.2024	001	New Release

Notice

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CLASSⅣ		CLASSII	

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 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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 - [d] the Products are exposed to high Electrostatic
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